

BQ29209-Q1 Voltage Protection with Automatic Cell Balance for 2-Series Cell Li-Ion Batteries

1 Features

- 2-series cell secondary protection
- Automatic cell imbalance correction with external enable control
 - ±30-mV enable, 0-mV disable thresholds typical
- · External capacitor-controlled delay timer
- External resistor-controlled cell balance current
- Low power consumption I_{CC} < 3 μA typical $(V_{CELL}(ALL) < V_{PROTECT})$
- · Internal cell balancing handles current up to 15 mA
- External cell balancing mode supported
- High-accuracy overvoltage protection:
 - ±25 mV with $T_A = 0$ °C to 60°C
- · Fixed overvoltage protection threshold: 4.30 V
- Small 8L DRB package
- Functional Safety-Capable
 - Documentation available to aid functional safety system design
- · Automotive-qualified AEC Q100 grade two

2 Applications

- 2nd level protection in li-ion battery packs
 - Emergency call (eCall)
 - Netbook computers
 - Power tools
 - Portable equipment and instrumentation
 - Battery backup systems

3 Description

The BQ29209-Q1 device is a secondary overvoltage protection IC for 2-series cell lithium-ion battery packs incorporates а high-accuracy precision overvoltage detection circuit and automatic cell imbalance correction.

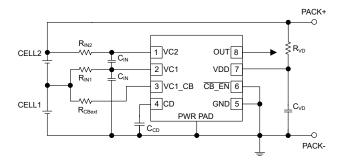
The voltage of each cell in a 2-series cell battery pack is compared to a factory programmed internal reference voltage. If either cell reaches an overvoltage condition, the OUT pin changes from low to high state.

The BQ29209-Q1 can perform automatic voltagebased cell imbalance correction. Balancing can start when the cell voltages are different by nominally 30 mV or more and stops when the difference is nominally 0 mV. Cell balancing is enabled and disabled by the CB EN pin.

Device Information

PART NUMBER (1)	PACKAGE	BODY SIZE (NOM)
BQ29209-Q1	VSON (8)	3.00 mm × 3.00 mm

For all available packages, see the orderable addendum at the end of the data sheet.



Simplified Schematic



1 Features	
	8.4 Device Functional Modes11
3 Description	
4 Revision History	
5 Device Options	
6 Pin Configuration and Functions	
Pin Functions	11 Layout14
7 Specifications	11.1 Layout Guidelines14
7.1 Absolute Maximum Ratings	11.2 Layout Example14
7.2 ESD Ratings	12 Device and Documentation Support15
7.3 Recommended Operating Conditions4	12.1 Documentation Support15
7.4 Thermal Information4	12.2 Receiving Notification of Documentation Updates 15
7.5 Electrical Characteristics	12.3 Support Resources15
7.6 Recommended Cell Balancing Configurations	12.4 Trademarks15
7.7 Typical Characteristics6	12.5 Electrostatic Discharge Caution15
8 Detailed Description	12.6 Glossary15
8.1 Overview	
8.2 Functional Block Diagram	
8.3 Feature Description	
4 Revision History	
NOTE: Page numbers for previous revisions may different control of the control of	ision D (September 2020) Page
NOTE: Page numbers for previous revisions may different control of the control of	
NOTE: Page numbers for previous revisions may different control of the control of	ision C (December 2018) Page
NOTE: Page numbers for previous revisions may different control of the control of	ision D (September 2020) Page
NOTE: Page numbers for previous revisions may different control of the control of	ision D (September 2020) page ision C (December 2018) not connected first in sequence
NOTE: Page numbers for previous revisions may difference of the control of the co	ision D (September 2020) page ision C (December 2018) not connected first in sequence
NOTE: Page numbers for previous revisions may differ Changes from Revision C (December 2018) to Rev. Added the functional safety capable information Changes from Revision B (November 2018) to Rev. Added a clarification regarding operation if GND is Changes from Revision A (March 2016) to Revision Changed component names in the Simplified Scheme.	ision D (September 2020) Page ision C (December 2018) not connected first in sequence
NOTE: Page numbers for previous revisions may difference of the commendation of the co	ision D (September 2020) page ision C (December 2018) not connected first in sequence

Changed external cell balancing figure, equations, and description......13 Changes from Revision * (June 2015) to Revision A (March 2016)

Page

Added Figure 8-2 to clarify the cell balancing description; updated the equations9



5 Device Options

T _A	T _A PART NUMBER			
-40°C to +105°C	BQ29209-Q1	4.3 V		

6 Pin Configuration and Functions

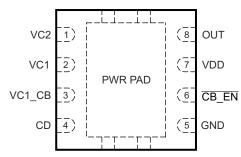


Figure 6-1. DRB Package 8-Pin VSON Top View

Pin Functions

PIN		DESCRIPTION
NAME	NO.	DESCRIPTION
CB_EN	6	Cell balance enable
CD	4	Connection to external capacitor for programmable delay time
GND	5	Ground pin
OUT	8	Output
Thermal Pad	PWR PAD	GND pin to be connected to the PWRPAD on the printed circuit board for proper operation
VC1	2	Sense voltage input for bottom cell
VC1_CB	3	Cell balance input for bottom cell
VC2	1	Sense voltage input for top cell
VDD	7	Power supply

7 Specifications

7.1 Absolute Maximum Ratings

Over-operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Supply voltage range, V _{MAX}	VDD-GND	-0.3	16	V
	VC2-GND, VC1-GND	-0.3	16	V
Input voltage range, V _{IN}	VC2-VC1, CD-GND	-0.3	8	V
	CB_EN-GND	-0.3	16	V
Output voltage range, V _{OUT}	OUT-GND	-0.3	16	V
Continuous total power dissipation,	ontinuous total power dissipation, P _{TOT} See Section 7.4.			
Storage temperature , T _{stg}	-65	150	°C	

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



7.2 ESD Ratings

				VALUE	UNIT
		Human-body model (HBM), per AEC Q100-002 ⁽¹⁾		±2000	
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per AEC	All pins	±500	v
(ESD)	•	Q100-011	Corner pins (VC2, CD, OUT, and GND)	±750	-

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

7.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
Supply voltage, VDD		4		10	V
Input voltage range	VC2-VC1, VC1-GND	0		5	V
Delay time capacitance, t _{d(CD)}	C _{CD} (See Figure 9-1.)		0.1		μF
Voltage monitor filter resistance	R _{IN} (See Figure 9-1.)	100	1K		Ω
Voltage monitor filter capacitance	C _{IN} (See Figure 9-1.)	0.01	0.1		μF
Supply voltage filter resistance	R _{VD} (See Figure 9-1.)		100	1K	Ω
Supply voltage filter capacitance	C _{VD} (See Figure 9-1.)		0.1		μF
Cell balance resistance	R _{CBext} (See Figure 9-1 and Section 8.3.1.)	100		4.7K	Ω
Operating ambient temperature ra	nge, T _A	-40		105	°C

7.4 Thermal Information

		BQ29209-Q1	
	THERMAL METRIC ⁽¹⁾	DRB	UNIT
		8 PINS	
R _{0JA}	Junction-to-ambient thermal resistance	50.5	°C/W
R _{0JC(top)}	Junction-to-case(top) thermal resistance	25.1	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	19.3	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.7	°C/W
ΨЈВ	Junction-to-board characterization parameter	18.9	°C/W
R _{θJC(bot)}	Junction-to-case(bottom) thermal resistance	5.2	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

7.5 Electrical Characteristics

Typical values stated where T_A = 25°C and VDD = 7.2 V. Minimum and maximum values stated where T_A = -40°C to 105°C and VDD = 4 V to 10 V (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{PROTECT}	Overvoltage detection voltage			4.3		V
V _{HYS}	Overvoltage detection hysteresis		200	300	400	mV
V _{OA}	Overvoltage detection accuracy	T _A = 25°C	-10		10	mV
.,	Overvoltage threshold	T _A = 0°C to 60°C	-0.4		0.4	mV°/C
V _{OA_DRIFT}	temperature drift	$T_A = -40^{\circ}C$ to 110°C	-0.6		0.6	IIIV /C
X _{DELAY}	Overvoltage delay time scale factor	T _A = 0°C to 60°C Note: Does not include external capacitor variation.	6 9		12	
		T _A = -40°C to 110°C Note: Does not include external capacitor variation.	5.5	9	13.5	s/µF

Submit Document Feedback

Typical values stated where T_A = 25°C and VDD = 7.2 V. Minimum and maximum values stated where T_A = -40°C to 105°C and VDD = 4 V to 10 V (unless otherwise noted).

The state of the s	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
X _{DELAY_CTM} ⁽¹⁾	Overvoltage delay time scale factor in Customer Test Mode			0.08		s/µF
I _{CD(CHG)}	Overvoltage detection charging current			150		nA
I _{CD(DSG)}	Overvoltage detection discharging current			60		μΑ
V_{CD}	Overvoltage detection external capacitor comparator threshold			1.2		V
I _{CC}	Supply current	(VC2-VC1) = (VC1-GND) = 3.5 V (See Figure 8-5.)		3	6	μA
		(VC2–VC1) or (VC1–GND) > V _{PROTECT} , VDD = 10 V, I _{OH} = 0	6	8.25	9.5	V
		(VC2–VC1) or (VC1–GND) = $V_{PROTECT}$, VDD = $V_{PROTECT}$, I_{OH} = -100 μ A, T_{A} = 0°C to 60°C	1.75	2.5		V
V _{OUT}	OUT pin drive voltage	(VC2–VC1) and (VC1–GND) < $V_{PROTECT}$, I_{OL} = 100 μ A, T_{A} = 25°C			200	mV
		(VC2–VC1) and (VC1–GND) < $V_{PROTECT}$, I_{OL} = 0 μ A, T_{A} = 25°C		0	10	mV
		VC2 = VC1 = VDD = 4 V, I _{OL} = 100 μA			200	mV
I _{OH}	High-level output current	OUT = 1.75 V, (VC2–VC1) or (VC1–GND) = V _{PROTECT} , VDD = V _{PROTECT} to 10 V, T _A = 0°C to 60°C	-100			μΑ
I _{OL}	Low-level output current	OUT = 0.05 V, (VC2–VC1) or (VC1–GND) < V _{PROTECT} , VDD = V _{PROTECT} to 10 V, T _A = 0°C to 60°C	30		85	μΑ
I _{OH_ZV}	High-level short-circuit output current	OUT = 0 V, (VC2–VC1) = (VC1–GND) = V _{PROTECT} VDD = 4 to 10 V			-8	mA
1	Input current at VCv pine	Measured at VC1, (VC2–VC1) = (VC1–GND) = 3.5 V, T_A = 0°C to 60°C (See Figure 8-5.)	-0.2		0.2	μΑ
I _{IN}	Input current at VCx pins	Measured at VC2, (VC2–VC1) = (VC1–GND) = 3.5 V, T _A = 0°C to 60°C (See Figure 8-5.)			2.5	μΑ
V _{MM_DET_ON}	Cell mismatch detection threshold for turning ON	(VC2–VC1) versus (VC1–GND) and vice-versa when cell balancing is enabled. VC2 = VDD = 7.6 V	17	30	45	mV
V _{MM_DET_OFF}	Cell mismatch detection threshold for turning OFF	Delta between (VC2–VC1) and (VC1–GND) when cell balancing is disabled. VC2 = VDD = 7.6 V	-9	0	9	mV
V _{CB_EN_ON}	Cell balance enable ON threshold	Active LOW pin at CB_EN			1	V
V _{CB_EN_OFF}	Cell balance enable OFF threshold	Active HIGH at CB_EN	2.2			V
I _{CB_EN}	Cell balance enable ON input current	CB_EN = GND (See Figure 8-6.)			0.2	μΑ
R _{CB1int}	Internal cell balance switch resistance	CB_EN = GND		300		Ω
R _{CB2int}	Internal cell balance switch resistance	CB_EN = GND		235		Ω

⁽¹⁾ Specified by design. Not 100% tested in production.

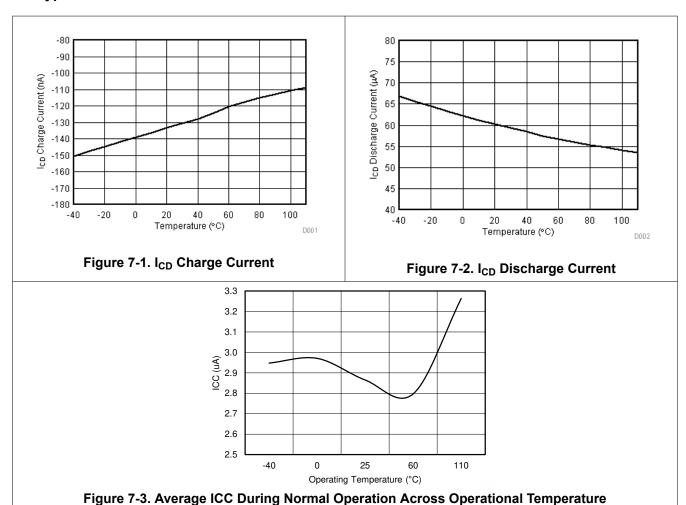


7.6 Recommended Cell Balancing Configurations

Typical values stated where T_A = 25°C and (VC2–VC1), (VC1–GND) = 3.8 V. Minimum and maximum values stated where T_A = -40°C to 105°C, VDD = 4 V to 10 V, and (VC2–VC1), (VC1–GND) = 3 V to 4.2 V. All values assume recommended supply voltage filter resistance R_{VD} of 100 Ω and 5% accurate or better cell balance resistor R_{CBext} .

			MIN	NOM	MAX	UNIT
I _{CB} Cell balance input curren		R _{CBext} = 4700 Ω	0.5	0.75	1	
		R _{CBext} = 2200 Ω	1	1.5	2	
		R _{CBext} = 910 Ω	2	3	4	
	R _{CBext} = 560 Ω	3	4.5	6	mA	
		R _{CBext} = 360 Ω	3.5	6	8.5	
		R _{CBext} = 240 Ω	4	7.5	11	
		R _{CBext} = 120 Ω	5	10	15	

7.7 Typical Characteristics



Submit Document Feedback

Copyright © 2020 Texas Instruments Incorporated

8 Detailed Description

8.1 Overview

The BQ29209-Q1 provides overvoltage protection and cell balancing for 2-series cell lithium-ion battery packs.

8.1.1 Voltage Protection

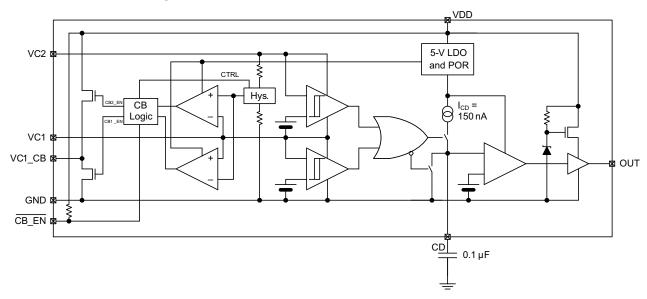
Each cell voltage is continuously compared to a factory configured internal reference threshold. If either cell reaches an overvoltage condition, the BQ29209-Q1 device starts a timer that provides a delay proportional to the capacitance on the CD pin. Upon expiration of the internal timer, the OUT pin changes from a low to high state.

8.1.2 Cell Balancing

If enabled, the BQ29209-Q1 performs automatic cell-balance correction where the two cells are automatically corrected for voltage imbalance by loading the cell with the higher voltage with a small balancing current. When the cells are measured to be equal within nominally 0 mV, the load current is removed. It will be re-applied if the imbalance exceeds nominally 30 mV. The cell mismatch correction circuitry is enabled by pulling the $\overline{\text{CB}}$ pin low, and disabled when $\overline{\text{CB}}$ $\overline{\text{EN}}$ is pulled to greater than 2.2 V, for example, VDD.

If the internal cell balancing current of up to 15 mA is insufficient, the BQ29209-Q1 may be configured via external circuitry to support much higher external cell balancing current.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Protection (OUT) Timing

Sizing the external capacitor is based on the desired delay time as follows:

$$C_{CD} = \frac{t_d}{X_{DELAY}}$$

Where t_d is the desired delay time and X_{DELAY} is the overvoltage delay time scale factor, expressed in seconds per microfarad. X_{DELAY} is nominally 9 s/ μ F. For example, if a nominal delay of 3 seconds is desired, use a C_{CD} capacitor that is 3 s / 9 s/ μ F = 0.33 μ F.

The delay time is calculated as follows:

$$t_d = C_{CD} \times X_{DELAY}$$

If the cell overvoltage condition is removed before the external capacitor reaches the reference voltage, the internal current source is disabled and an internal discharge block is employed to discharge the external capacitor down to 0 V. In this instance, the OUT pin remains in a low state.

8.3.2 Cell Voltage > V_{PROTECT}

When one or both of the cell voltages rises above $V_{PROTECT}$, the internal comparator is tripped, and the delay begins to count to t_d . If the input remains above $V_{PROTECT}$ for the duration of t_d , the BQ29209-Q1 output changes from a low to a high state, by means of an internal pull-up network, to a regulated voltage of no more than 9.5 V when $I_{OH} = 0$ mA.

The external delay capacitor should charge up to no more than the internal LDO voltage (approximately 5 V typically), and will fully discharge in approximately under 100 ms when the overvoltage condition is removed.

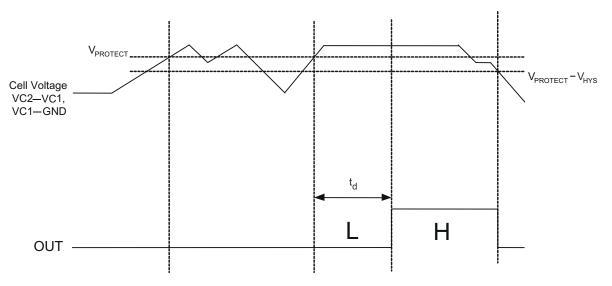


Figure 8-1. Timing for Overvoltage Sensing

8.3.3 Cell Connection Sequence

Note

Before connecting the cells, populate the overvoltage delay timing capacitor, C_{CD}.

The recommended cell connection sequence begins from the bottom of the stack, as follows:

- 1. GND
- 2. VC1
- 3. VC2

While not advised, connecting the cells in a sequence other than that described above does not result in errant activity on the OUT pin. For example:

- 1. GND
- 2. VC2 or VC1
- 3. Remaining VCx pin

Note

Using any cell connection sequence that does not connect GND first may result in increased leakage current drawn by the VDD pin.

8.3.4 Cell Balance Enable Control

To avoid prematurely discharging the cells, it is recommended to turn off (pull high) the active-low Cell Balance Enable Control pin at lower state-of-charge (SOC) levels.

8.3.5 Cell Balance Configuration

The following cell balancing details relate to Figure 8-2.

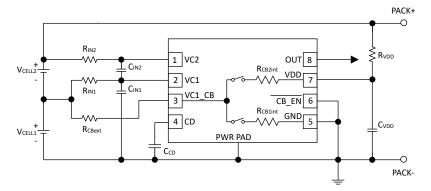


Figure 8-2. Simplified Schematic for Cell Balancing Description

The cell balancing current may be calculated as follows:

For Cell 1 balancing current, I_{CB1}:

$$I_{CB1} = \frac{V_{CELL1}}{R_{CBext} + R_{CB1int}}$$

(1)

For Cell 2 balancing current, I_{CB2}:

$$I_{CB2} = \frac{V_{CELL2}}{R_{CBext} + R_{CB2int} + R_{VDD}}$$

(2)

Where:

R_{CBext} = resistor connected between the top of Cell 1 and the VC1_CB pin

R_{IN1} = resistor connected between the top of Cell 1 and the VC1 pin

 R_{IN2} = resistor connected between the top of Cell 2 and the VC2 pin

 R_{VDD} = resistor connected between the top of Cell 2 and the VDD pin

8.3.6 Cell Imbalance Auto-Detection (Via Cell Voltage)

The $V_{MM_DET_ON}$ and $V_{MM_DET_OFF}$ specifications are calibrated where VDD = VC2 = 7.6 V and VC1 = 3.8 V. The recommended range of cell balancing is VC2 and VDD between 6.0 V and 8.4 V, and VC1 between 3 V and 4.2 V. Below VDD = 6 V, it is recommended to pull $\overline{CB_EN}$ high to disable the cell balancing function.

Copyright © 2020 Texas Instruments Incorporated

Submit Document Feedback



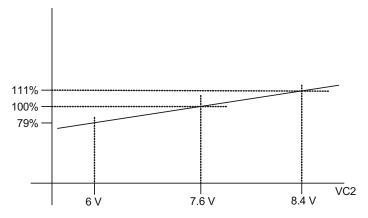


Figure 8-3. $V_{MM\ DET\ ON}$ and $V_{MM\ DET\ OFF}$ Threshold

8.3.7 Customer Test Mode

Customer Test Mode (CTM) helps to greatly reduce the overvoltage detection delay time and enable quicker customer production testing. This mode is intended for quick-pass board-level verification tests, and, as such, individual cell overvoltage levels may deviate slightly from the specifications (V_{PROTECT}, V_{OA}). If accurate overvoltage thresholds are to be tested, use the standard delay settings that are intended for normal use.

To enter CTM, VDD should be set to approximately 9.5 V higher than VC2. When CTM is entered, the device switches from the normal overvoltage delay time scale factor, X_{DELAY} , to a significantly reduced factor of approximately 0.08, thereby reducing the delay time during an overvoltage condition.

CAUTION

Avoid exceeding any Absolute Maximum Voltages on any pins when placing the part into CTM. Also, avoid exceeding absolute maximum voltages for the individual cell voltages (VC1–GND) and (VC2–VC1). Stressing the pins beyond the rated limits may cause permanent damage to the device.

To exit CTM, power off the device and then power it back on.

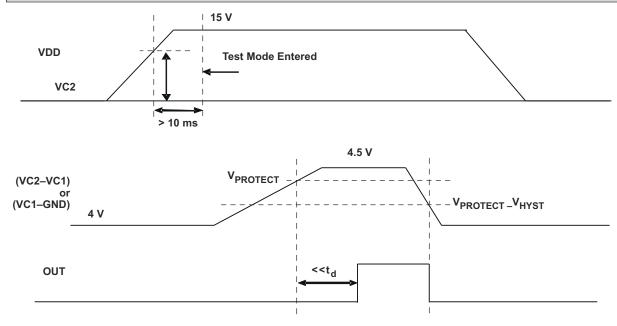


Figure 8-4. Voltage Test Limits

8.3.8 Test Conditions

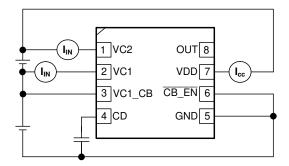


Figure 8-5. I_{CC}, I_{IN} Measurement

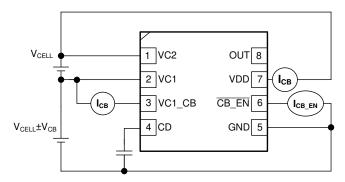


Figure 8-6. I_{CB} Measurement

8.4 Device Functional Modes

This device monitors the voltage of the cells connected to the VCx pins and depending on these voltages and the overall battery voltage at VDD the device enters different operating modes.

8.4.1 NORMAL Mode

The device is operating in NORMAL mode when the cell voltage range is between the over-charge detection threshold ($V_{PROTECT}$) and the minimum supply voltage.

If this condition is satisfied, the device turns OFF the OUT pin.

8.4.2 PROTECTION Mode

The device is operating in PROTECTION mode when the cell over voltage protection feature has been triggered. See *Section 8.3.2* for more details on this feature.

If this condition is satisfied, the device turns ON the OUT pin.

9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The BQ29209-Q1 is designed to be used in 2-series Li-lon battery packs and with the option to include voltage-based cell balancing. The number of parallel cells or the overall capacity of the battery only affects the cell balancing circuit due to the level of potential imbalance that needs to be corrected.



9.2 Typical Applications

9.2.1 Battery Connection

Figure 9-1 shows the configuration for the 2-series cell battery connection with cell balancing enabled.

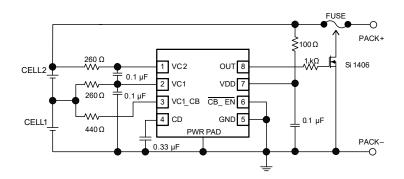


Figure 9-1. 2-Series Cell Configuration

9.2.1.1 Design Requirements

For this design example, use the parameters listed in Table 9-1.

 Table 9-1. Design Parameters

 DESIGN PARAMETER
 EXAMPLE VALUE at $T_A = 25^{\circ}C$

 Input voltage range
 4 V to 10 V

 Overvoltage Protection (OVT)
 4.3 V

 Overvoltage detection delay time
 3 s

 Overvoltage detection delay timer capacitor
 0.33 μF

 Cell Balancing Enabled
 Yes

 Cell Balancing Current, I_{CB1} and I_{CB2} 5 mA (targeted at a nominal cell voltage of 3.8 V)

 Cell Balancing Resistors, R_{CBext} , R_{IN1} , R_{IN2} and R_{VD} $R_{CBext} = 440 \Omega$, $R_{IN1} = 260 \Omega$, $R_{IN2} = 260 \Omega$, $R_{VD} = 100 \Omega$

Table 9-1. Design Parameters

9.2.1.2 Detailed Design Procedure

The BQ29209-Q1 has limited features but there are some key calculations to be made when selecting external component values.

- Calculate the required C_{CD} capacitor value for the voltage protection delay time. Care should be taken to evaluate the tolerances of the capacitor and the BQ29209-Q1 to ensure system specifications are met.
- Calculate the cell balancing resistor values to provide a suitable level of balancing current that will, at a minimum, counter act an increase in imbalance during normal operation of the battery. Care should be taken to ensure any connectivity resistance is also considered as this will also reduce the balancing current level.

Submit Document Feedback

Copyright © 2020 Texas Instruments Incorporated

9.2.1.3 Application Curve

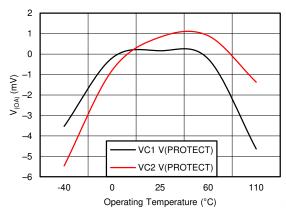


Figure 9-2. Average V_{PROTECT} Accuracy (V_{OA}) Across Operation Temperature

9.3 System Example

9.3.1 External Cell Balancing

Higher cell balancing currents can be supported by means of a simple external network, as shown in Figure 9-3.

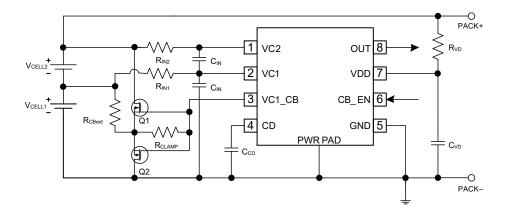


Figure 9-3. External Cell Balancing Configuration

The VC1_CB pin is tri-stated when cell balancing is disabled, is driven low by the internal logic to enable balancing on CELL1, and is driven high by the internal logic to enable balancing on CELL2. R_{CLAMP} ensures that both Q1 and Q2 remain off when balancing is disabled, and should be sized above 2 k Ω to prevent excessive internal device current when the balancing network is activated. If R_{CLAMP} is too small, then the gate-source voltage required to enable the external FETs cannot be achieved. R_{CBext} determines the value of the balancing current, and is dependent on the voltage of the balanced cell and the specific Q1 and Q2 transistors used in the design (due to the transistors operating in saturation mode during balancing). The balancing currents (assuming the current through R_{CLAMP} is not significant) are given as follows:



$$I_{CB1} = \frac{(V_{CELL1} - V_{SG_Q2})}{R_{CBext}}$$

(3)

$$I_{CB2} = \frac{(V_{CELL2} - V_{GS_Q1})}{R_{CBext}}$$

(4)

10 Power Supply Recommendations

The recommended power supply for this device is a maximum 10-V operation on the VDD input pin.

11 Layout

11.1 Layout Guidelines

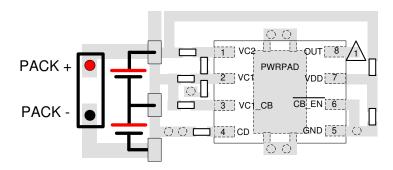
The following are the recommended layout guidelines:

- 1. Ensure the input filters to the VC1 and VC2 pins are as close to the IC as possible to improve noise immunity.
- 2. If the OUT pin is used to control a high current path, for example: to blow a chemical fuse, then care should be taken to ensure the high current path creates minimal interference of the BQ29209-Q1 voltage sense inputs.
- 3. The input RC filter on the VDD pin should be close to the terminal of the IC.

11.2 Layout Example

Additional circuitry required based on usage of the OUT pin

Via connects between two layers



12 Device and Documentation Support

12.1 Documentation Support

For additional information, see the following related document:

BQ29209-Q1 Functional Safety FIT Rate, FMD, and Pin FMA Application Report

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

12.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com 31-Oct-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow	Peak reflow	
						(4)	(5)		
BQ29209TDRBRQ1	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 105	209Q1
BQ29209TDRBRQ1.A	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 105	209Q1
BQ29209TDRBTQ1	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 105	209Q1
BQ29209TDRBTQ1.A	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 105	209Q1
BQ29209TDRBTQ1.B	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 105	209Q1

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE OPTION ADDENDUM

www.ti.com 31-Oct-2025

OTHER QUALIFIED VERSIONS OF BQ29209-Q1:

● Catalog : BQ29209

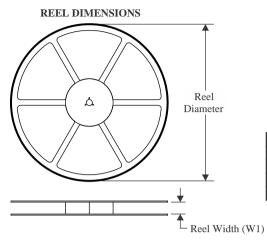
NOTE: Qualified Version Definitions:

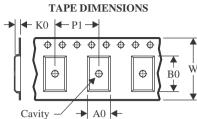
• Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

www.ti.com 20-Apr-2023

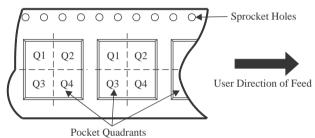
TAPE AND REEL INFORMATION





	•
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

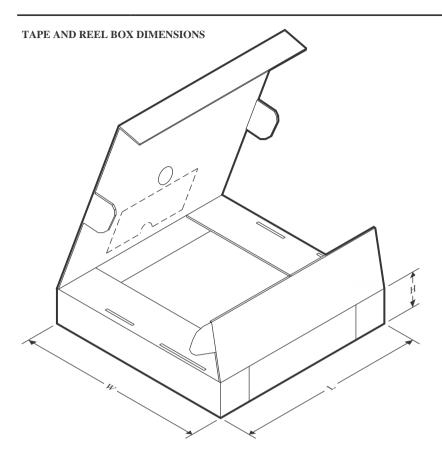
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
BQ29209TDRBRQ1	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
BQ29209TDRBTQ1	SON	DRB	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

www.ti.com 20-Apr-2023



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
BQ29209TDRBRQ1	SON	DRB	8	3000	346.0	346.0	33.0
BQ29209TDRBTQ1	SON	DRB	8	250	210.0	185.0	35.0



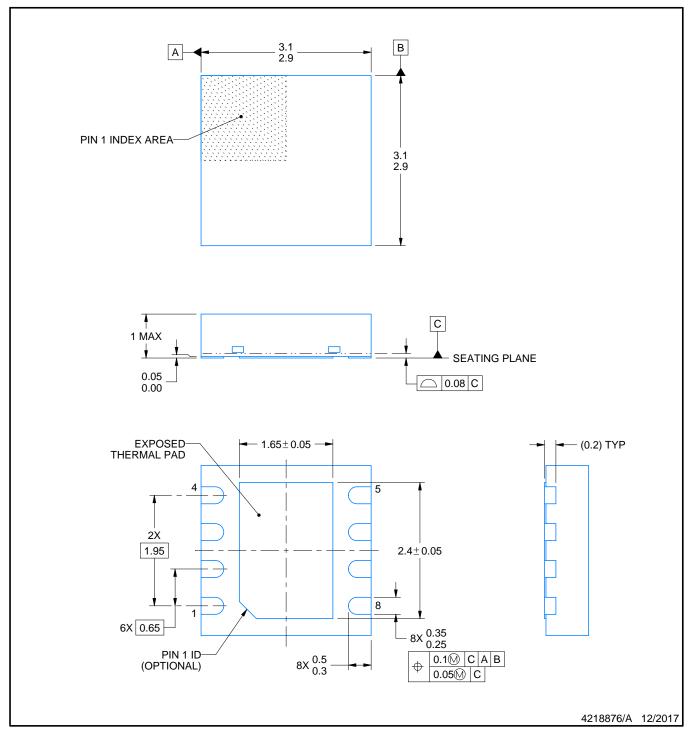
Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4203482/L





PLASTIC SMALL OUTLINE - NO LEAD

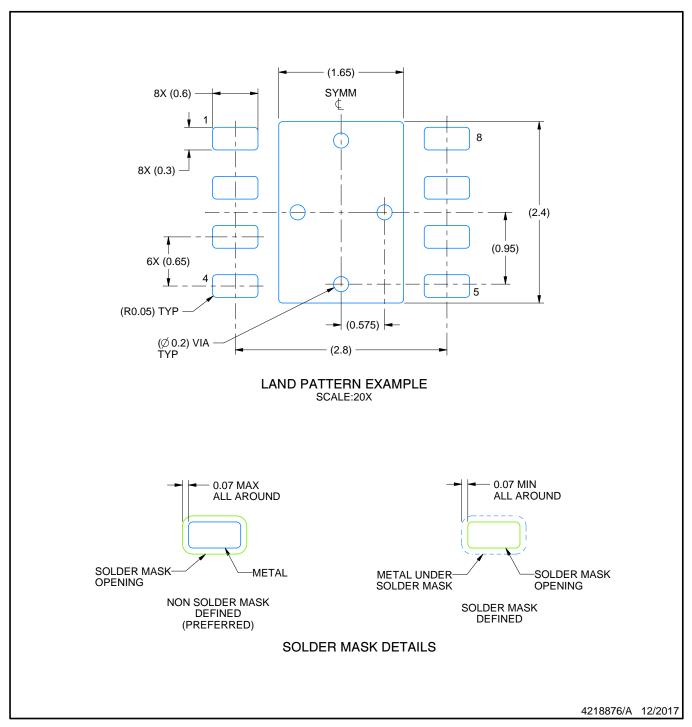


NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC SMALL OUTLINE - NO LEAD

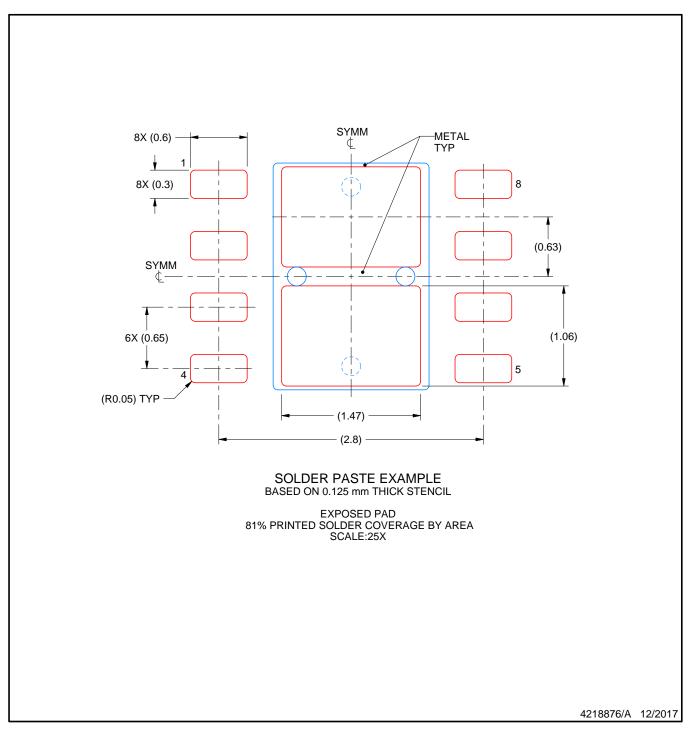


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale, TI's General Quality Guidelines, or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2025, Texas Instruments Incorporated

Last updated 10/2025